NSN 5961-00-777-5532

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-777-5532 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 0.600 inches **Overall Diameter:** 0.150 inches **End Application:** General purpose electronic test equipment gpete **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 100.00 microamperes forward current, average peak **Special Features:** voltage; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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